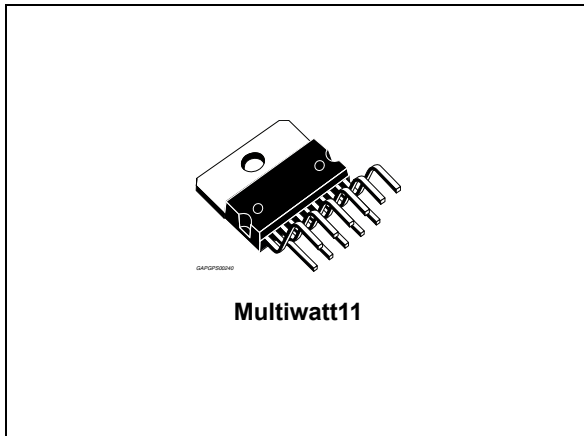


35 W bridge car radio amplifier

Datasheet - production data



Features

- High power capability:
 - 40 W/4 Ω max
 - 35 W/4 Ω EIAJ
 - 45 W/3.2 Ω max
 - 40 W/3.2 Ω EIAJ
 - 32 W/3.2 Ω @ $V_S = 14.4$ V, $f = 1$ kHz, $d = 10$ %
 - 26 W/4 Ω @ $V_S = 14.4$ V, $f = 1$ kHz, $d = 10$ %
- Differential inputs (either single ended or differential input signal are accepted)
- Minimum external component count:
 - No bootstrap capacitors
 - No Boucherot cells

- Internally fixed gain (30 dB)
- No SVR Capacitor
- Standby function (CMOS compatible)
- Programmable turn-on/off delay
- No audible pop during mute and standby operations
- Protections:
 - Short circuit (to GND, to V_S , across the load)
 - Very inductive loads
 - Chip over temperature
 - Load dump
 - Open GND
 - ESD

Description

The TDA7391 is a bridge class AB audio power amplifier specially intended for car radio high power applications.

The high power capability together with the possibility to operate either in differential input mode or single ended input mode makes it suitable for boosters and high end car radio equipments. The exclusive fully complementary output stage and the internal fixed gain configuration drop the external component count.

The on board clipping detector allows easy implementation of gain compression systems.

Table 1. Device summary

Order code	Package	Packing
TDA7391	Multiwatt11 (vertical)	Tube

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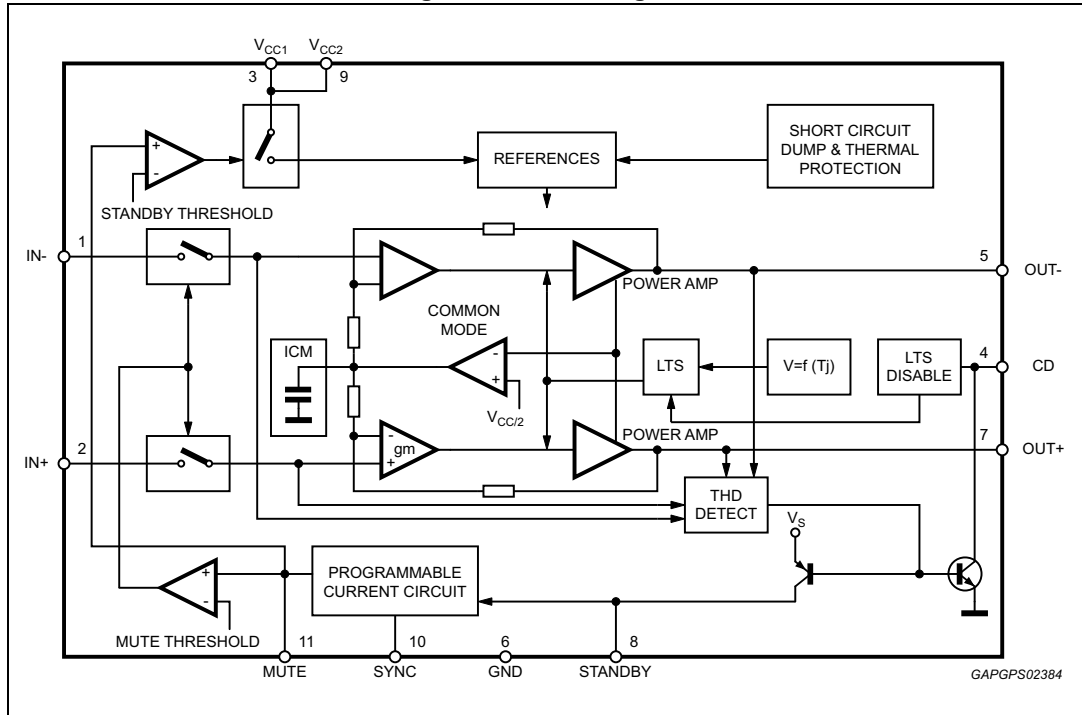
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1 Block and pin description diagrams

1.1 Block diagram

Figure 1. Block diagram



1.2 Pin description

Figure 2. Pin connection (top view)

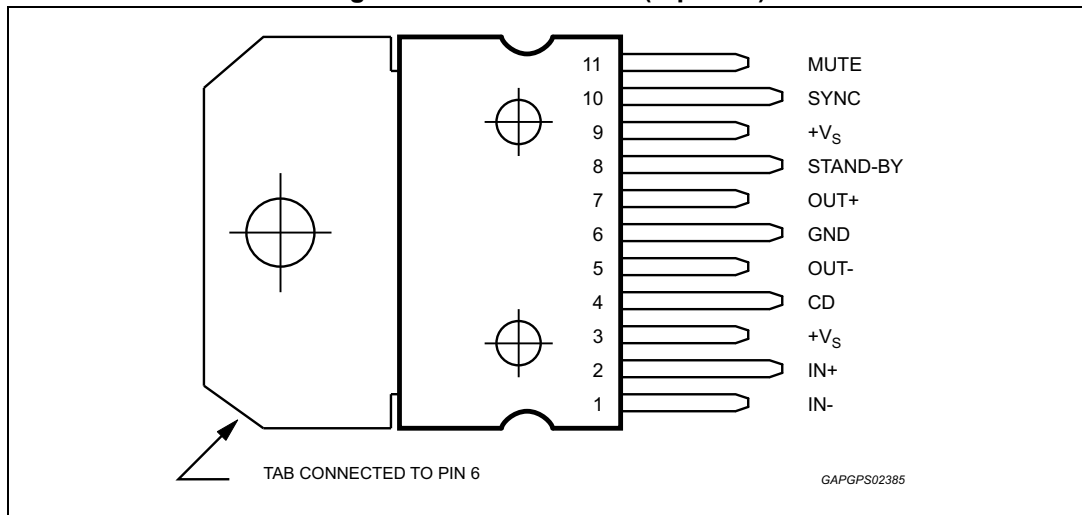


Table 2. Pin functional description

Pin#	Pin name	Description
1, 2	INPUTS	The input stage is a high impedance type also capable of operation in single ended mode with one input capacitively coupled to the signal GND. The impedance seen by the inverting and non inverting input pins must be matched.
3,9	+V	Supply voltage.
4	CD	The TDA7391 is equipped with a diagnostic circuitry able to detect the clipping in the Output Signal (distortion = 10%). The CD pin (open collector) gives out low level signal during clipping.
5, 7	OUTPUTS	The output stage is a bridge type able to drive loads as low as 3.2Ω . It consists of two class AB fully complementary PNP/NPN stages fully protected. A rail to rail output voltage swing is achieved without need of bootstrap capacitors. No external compensation is necessary.
6	GND	Ground.
8	STAND-BY	The device features a standby function which shuts down all the internal bias supplies when the STAND-BY pin is low. In standby mode the amplifier sinks a small current (in the range of few μA). When the STAND-BY pin is high the IC becomes fully operational.
10	SYNC	A resistor (R_2) has to be connect between pin 10 and GND in order to program the current that flows in the C_3 capacitor (pin 11). The values of C_3 and R_2 determine the time required to bias the amplifier.
11	MUTE	The pin will have a capacitor (C_3) tied to GND to set the MUTE/STAND-BY time. An automatic Mute during turn on/off is provided to prevent noisy transients.

2 Electrical specifications

2.1 Absolute maximum ratings

Table 3. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V_S	DC supply voltage	28	V
V_{OP}	Operating supply voltage	18	V
V_{PEAK}	Peak supply voltage (t = 50 ms)	50	V
I_O	Output peak current repetitive (f > 10 Hz)	4.5	A
	Output peak current non repetitive	6	A
P_{tot}	Power dissipation ($T_{case} = 85\text{ °C}$)	43	W
T_{stg}, T_j	Storage and junction temperature ⁽¹⁾	-40 to 150	°C
T_{amb}	Operative ambient temperature range	-40 to 105	°C

1. A suitable heatsink/dissipation system should be used to keep T_j inside specified limits.

2.2 Thermal data

Table 4. Thermal data

Symbol	Parameter	Value	Unit
$R_{th\ j-case}$	Thermal resistance junction to case	Max 1.8	°C/W

2.3 Electrical characteristics

Refer to the test circuit, $V_S = 14.4\text{ V}$; $R_L = 4\ \Omega$, $f = 1\text{ kHz}$, $T_{amb} = 25\text{ °C}$; unless otherwise specified.

Table 5. Electrical characteristics

Symbol	Parameter	Test condition	Min.	Typ.	Max.	Unit
V_S	Supply voltage range	-	8	-	18	V
I_q	Total quiescent current	-	-	60	150	mA
V_{OS}	Output offset voltage	-	-	-	120	mV
I_{SB}	Standby current	$V_{ST-BY} = 1.5\text{ V}$	-	-	100	μA
I_{SBin}	Standby input bias current	$V_{ST-BY} = 5\text{ V}$	-	-	10	μA
V_{SBon}	Standby On threshold voltage	-	-	-	1.5	V
V_{SBoff}	Standby Off threshold voltage	-	3.5	-	-	V
ATT_{ST-BY}	Standby attenuation	-	--	90	-	dB
I_{M_in}	Mute input bias current	$V_{MUTE} = 5\text{ V}$	-	-	10	μA

Table 5. Electrical characteristics (continued)

Symbol	Parameter	Test condition	Min.	Typ.	Max.	Unit
A_M	Mute attenuation	-	-	90	-	dB
P_O	Output power	$d = 10\%$	20	26	-	W
		$d = 1\%$	-	21	-	W
		$d = 10\%; R_L = 3.2\ \Omega$	-	32	-	W
$P_{O\ EIAJ}$	EIAJ output power ⁽¹⁾	$V_S = 13.7\ V; R_L = 3.2\ \Omega$	-	40	-	W
$P_{O\ MAX}$	Max. output power ⁽¹⁾	$V_S = 14.4\ V; R_L = 3.2\ \Omega$	-	45	-	W
d	Distortion	-	-	0.06	-	%
		$P_O = 0.1\ \text{to}\ 15\ W$	-	0.03	-	%
G_V	Voltage gain	-	29.5	30	30.5	dB
f_H	High frequency roll-off	$P_O = 1W; -3dB$	75	-	-	kHz
R_{IN}	Input Impedance	Differential	36	60	-	k Ω
		Single Ended	30	55	-	k Ω
E_{IN}	Input noise voltage	$R_g = 0\ \Omega; f = 22\ Hz\ \text{to}\ 22\ kHz$	-	4	-	mV
CMRR	Input common mode rejection	$f = 1\ kHz; V_{IN} = 1\ V_{rms}$	-	65	-	dB
SVR	Supply voltage rejection	$R_g = 0\ \Omega; V_r = 1\ V_{rms}$	-	60	-	dB
CDL	Clipping detection level	-	5	10	15	%
T_{sd}	Absolute thermal shutdown junction temperature	-	-	160	-	$^{\circ}C$

1. Saturated square wave output.

Figure 3. Test and application circuit

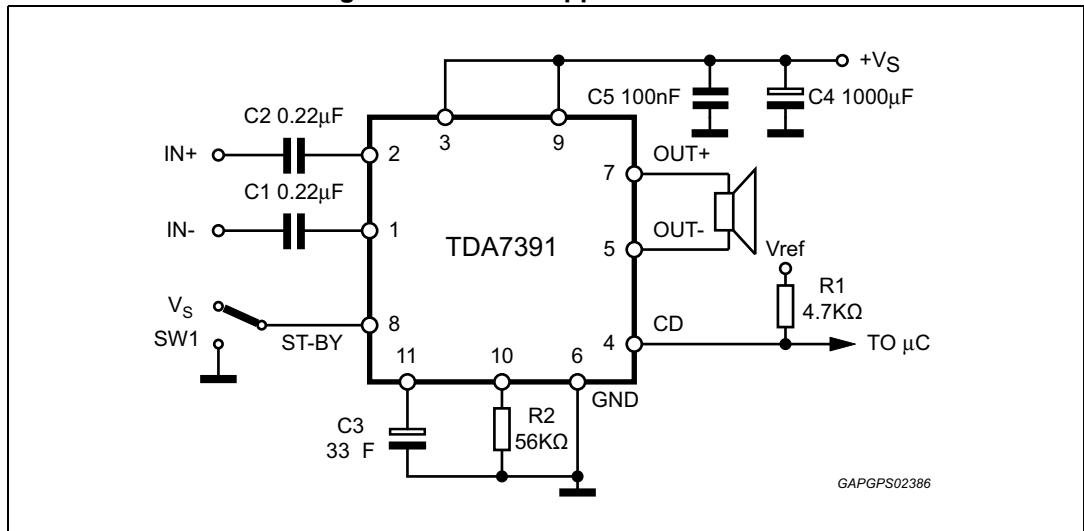
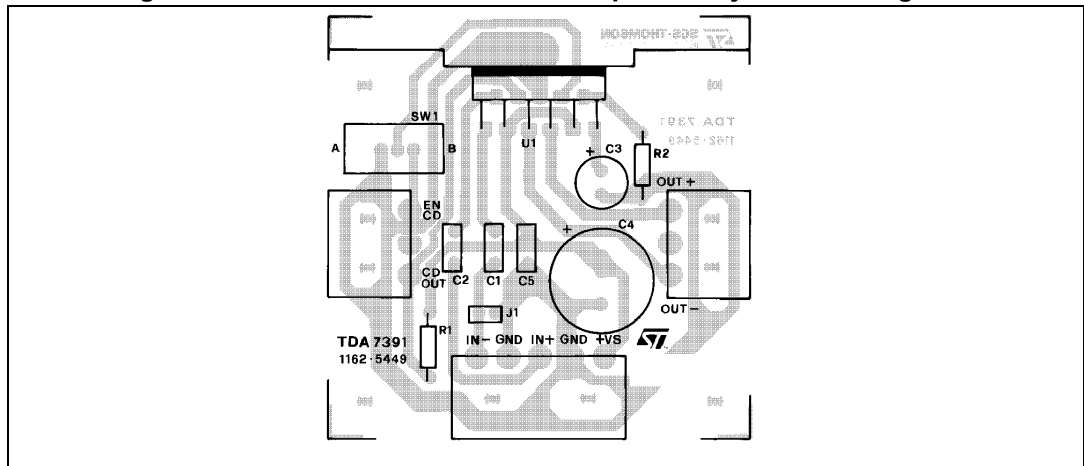


Figure 4. Printed circuit board and component layout of the Figure 4



2.4 Electrical characteristics curves

Figure 5. Quiescent current vs. supply voltage

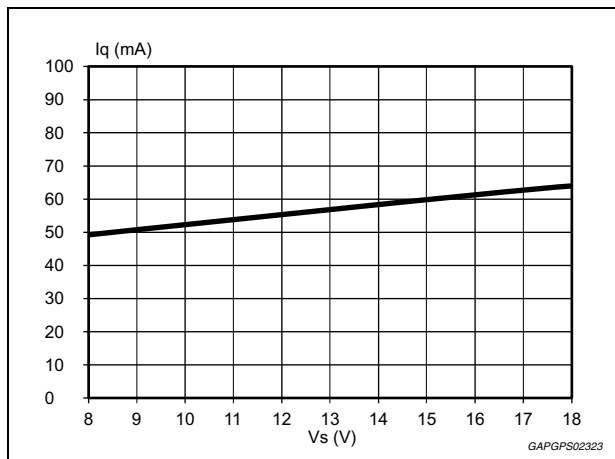


Figure 7. Output power vs. supply voltage ($R_L = 4 \Omega$)

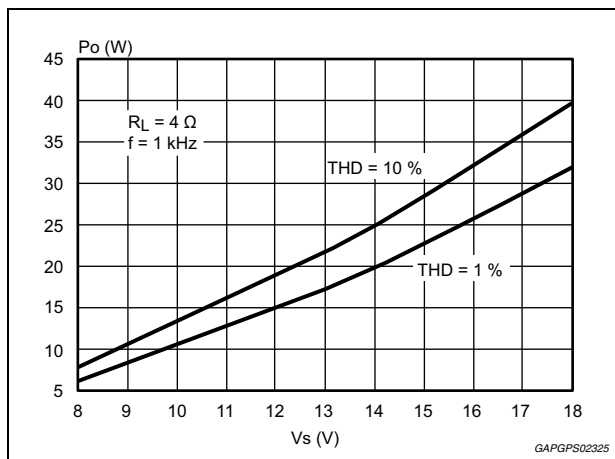


Figure 6. EIAJ power vs. supply voltage

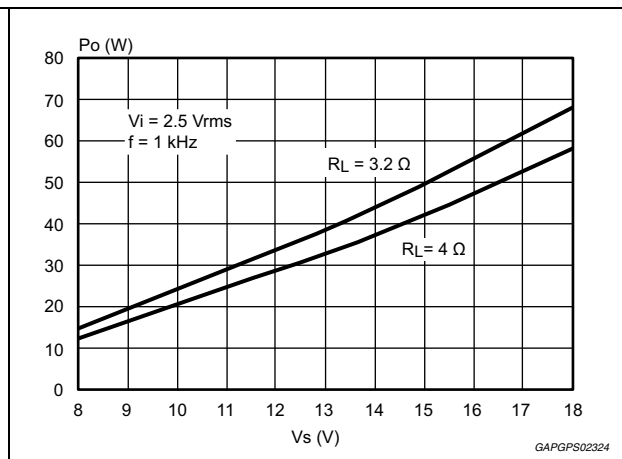


Figure 8. Distortion vs. frequency ($R_L = 4 \Omega$)

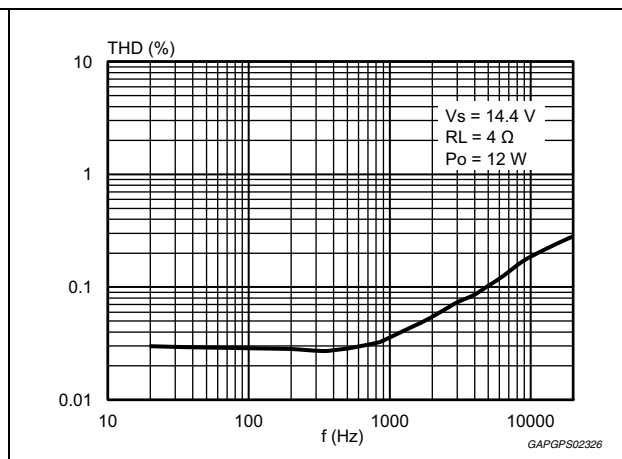


Figure 9. Output power vs. supply voltage
($R_L = 3.2 \Omega$)

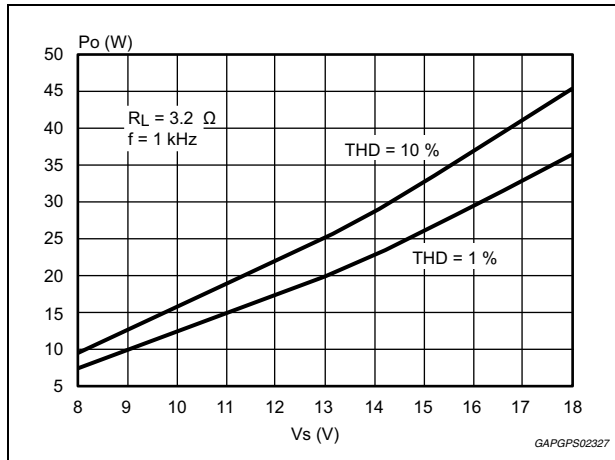


Figure 10. Distortion vs. frequency
($R_L = 3.2 \Omega$)

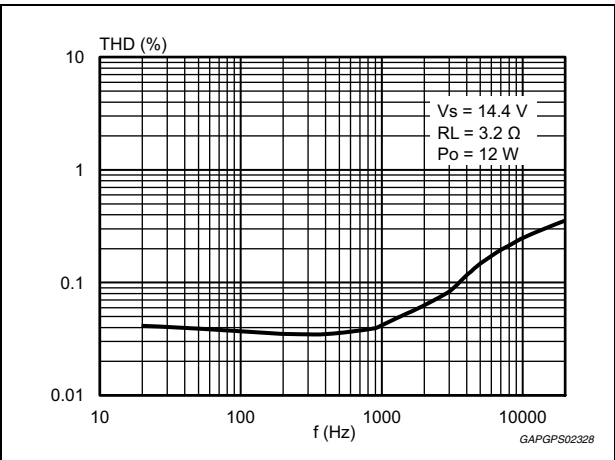


Figure 11. Supply voltage rejection vs. frequency

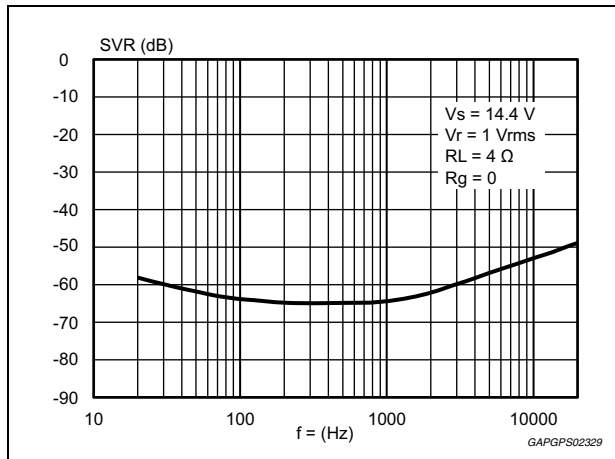


Figure 12. Common mode rejection vs. frequency

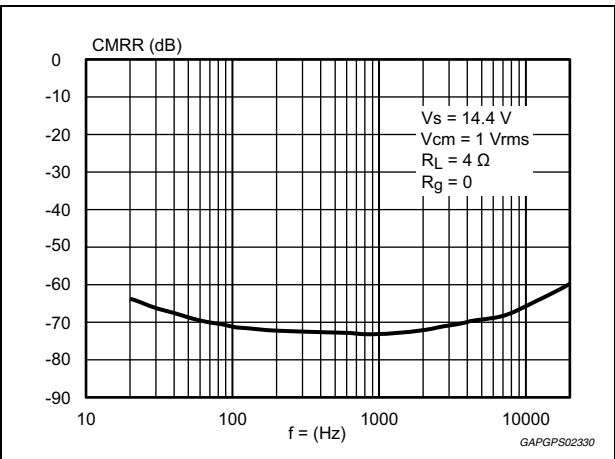


Figure 13. Total power dissipation and efficiency vs. output power ($R_L = 4 \Omega$)

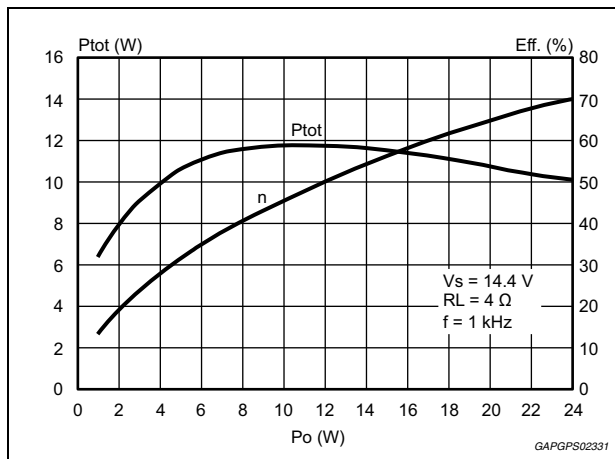
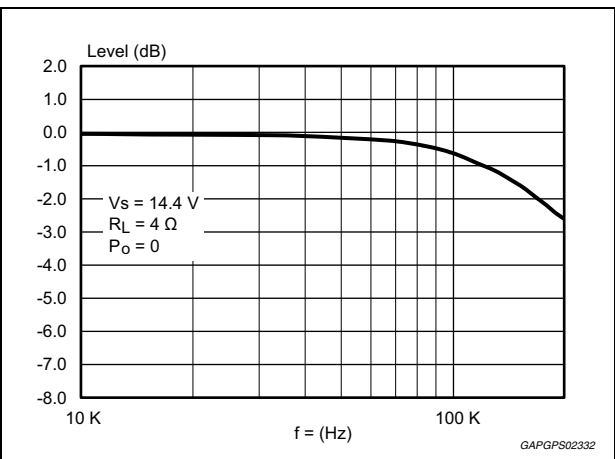


Figure 14. Power bandwidth

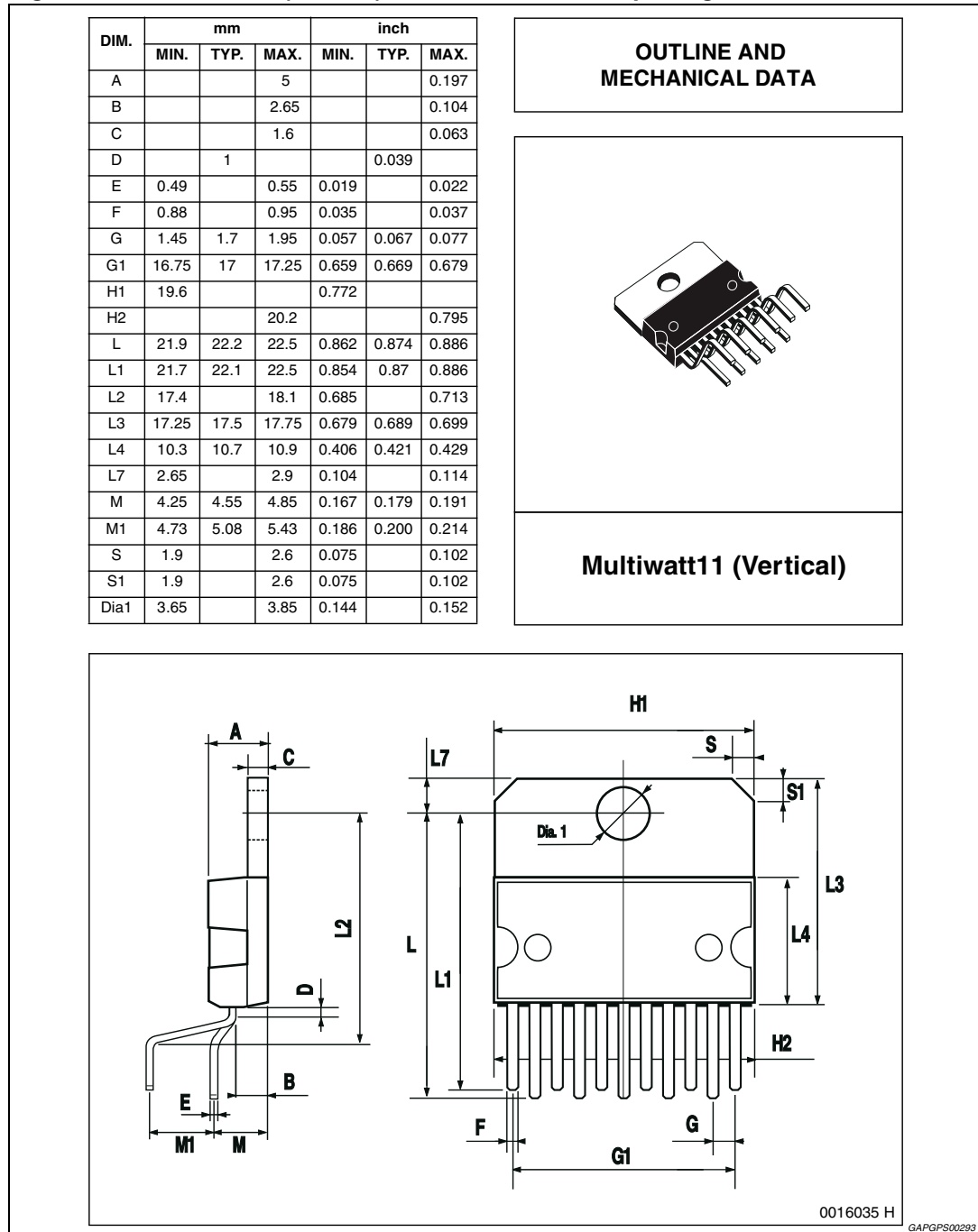


3 Package information

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Figure 15. Multiwatt11 (vertical) mechanical data and package dimensions



4 Revision history

Table 6. Document revision history

Date	Revision	Changes
24-May1998	3	Initial release.
19-Jun-2013	4	Updated Table 3: Absolute maximum ratings on page 7 .

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